Features

- 3.0V to 5.5V Operating Range
- Advanced Low-voltage Electrically-erasable Programmable Logic Device
- User-controlled Power-down Pin Option
- Pin-controlled Standby Power (10 μA Typical)
- Well-suited for Battery Powered Systems
- 10 ns Maximum Propagation Delay
- CMOS and TTL Compatible Inputs and Outputs
- Latch Feature Hold Inputs to Previous Logic States
- Advanced Electrically-erasable Technology
 - Reprogrammable
 - 100% Tested
- High-reliability CMOS Process
 - 20 Year Data Retention
 - 100 Erase/Write Cycles
 - 2,000V ESD Protection
 - 200 mA Latchup Immunity
- Commercial and Industrial Temperature Ranges
- Dual-in-line and Surface Mount Packages in Standard Pinouts
- Inputs are 5V Tolerant
- True Input Transition Detection "QZ" Version
- Green Package Options (Pb/Halide-free/RoHS Compliant) Available

1. Description

The ATF22LV10C is a high-performance CMOS (electrically-erasable) programmable logic device (PLD) that utilizes Atmel's proven electrically-erasable Flash memory technology. Speeds down to 10 ns and power dissipation as low as 10 mA are offered. All speed ranges are specified over the 3.0V to 5.5V range for industrial and commercial temperature ranges.

The ATF22LV10C provides a low-voltage and user controlled "zero" power CMOS PLD solution. A user-controlled power-down feature offers "zero" (5 mA typical) standby power. This feature allows the user to manage total system power to meet specific application requirements and enhance reliability, all without sacrificing speed. (The ATF22LV10CZ provides edge-sensing "zero" standby power (10 mA typical), as well as low voltage operation. See the ATF22LV10CZ datasheet.)

The ATF22LV10C is capable of operating at supply voltages down to 3.0V. When the power-down pin is active, the device is placed into a zero standby power-down mode. When the power-down pin is not used or active, the device operates in a full power low voltage mode. Pin "keeper" circuits on input and output pins hold pins to their previous logic levels when idle, which eliminate static power consumed by pull-up resistors.

The ATF22LV10C macrocell incorporates a variable product term architecture. Each output is allocated from 8 to 16 product terms which allows highly-complex logic functions to be realized. Two additional product terms are included to provide synchronous reset and asynchronous reset. These additional product terms are common to all 10 registers and are automatically cleared upon power-up. Register preload simplifies testing. A security fuse prevents unauthorized copying of programmed fuse patterns.



Highperformance EE PLD

ATF22LV10C

See separate datasheet for ATF22LV10CQZ option.



3. Absolute Maximum Ratings*

Temperature Under Bias40°C to +85°C
Storage Temperature65°C to +150°C
Voltage on Any Pin with Respect to Ground2.0V to +7.0V ⁽¹⁾
Voltage on Input Pins with Respect to Ground During Programming2.0V to +14.0V ⁽¹⁾
Programming Voltage with Respect to Ground2.0V to +14.0V ⁽¹⁾

*NOTICE:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note: 1.

Minimum voltage is -0.6V DC, which may undershoot to -2.0V for pulses of less than 20 ns.
 Maximum output pin voltage is V_{CC} + 0.75V DC, which may overshoot to 7.0V for pulses of less than 20 ns.

4. DC and AC Operating Conditions

	Commercial	Industrial
Operating Temperature (Ambient)	0°C - 70°C	-40°C - 85°C
V _{CC} Power Supply	3.0V - 5.5V	3.0V - 5.5V

4.1 DC Characteristics

Symbol	Parameter	Condition ⁽²⁾	Condition ⁽²⁾		Тур	Max	Units
I _{IL}	Input or I/O Low Leakage Current	$0 \le V_{IN} \le V_{IL}(Max)$				-10	μΑ
I _{IH}	Input or I/O High Leakage Current	$(V_{CC} - 0.2)V \le V_{IN} \le V_{CC}$				10	μΑ
I _{CC}	Power Supply Current	V _{CC} = Max, V _{IN} = Max Outputs Open	Com. Ind.		55 60	85 90	mA mA
I _{CC2}	Clocked Power Supply Current	V _{CC} = Max, Outputs Open, f = 15 MHz	Com.			100 105	mA mA
I _{PD}	Power Supply Current, Power-down Mode	V _{CC} = Max, V _{IN} = 0, Outputs Open	Com.		10 10	100 100	μA μA
I _{OS} ⁽¹⁾	Output Short Circuit Current	V _{OUT} = 0.5V				-130	mA
V _{IL}	Input Low Voltage			-0.5		0.8	V
V _{IH}	Input High Voltage			2.0		V _{CC} + 0.75	V
V _{OL}	Output Low Voltage	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = \text{Min}$ $I_{OL} = 16 \text{ mA}$				0.5	V
V _{OH}	Output High Voltage	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{CC} = \text{Min}$ $I_{OH} = -2.0 \text{ mA}$		2.4			V
V _{OH}	Output High Voltage	I _{OH} = -100 μA		V _{CC} - 0.2V			V

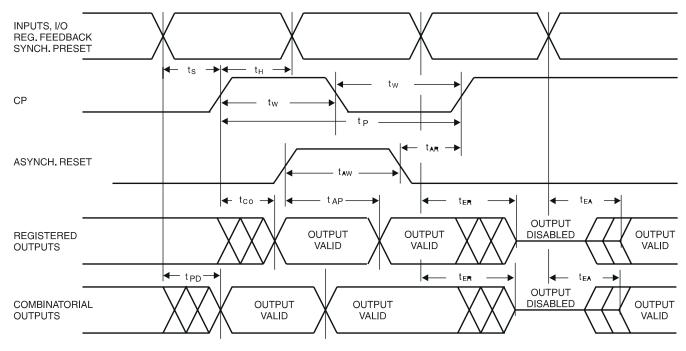
Notes: 1. Not more than one output at a time should be shorted. Duration of short circuit test should not exceed 30 sec.

^{2.} For DC characteristics, the test condition of V_{CC} = Max corresponds to 3.6V.





4.2 AC Waveforms



4.3 AC Characteristics⁽¹⁾

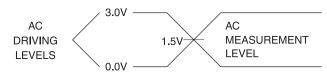
		-	-10		-15	
Symbol	Parameter	Min	Max	Min	Max	Units
t _{PD}	Input or Feedback to Non-Registered Output	3	10	3	15	ns
t _{CF}	Clock to Feedback		5		8	ns
t _{CO}	Clock to Output	2	6.5	2	10	ns
t _S	Input or Feedback Setup Time	7.5		12		ns
t _H	Input Hold Time	0		0		ns
t _P	Clock Period	12		16		ns
t _W	Clock Width	6		8		ns
	External Feedback 1/(t _S + t _{CO})		71.4		45.5	MHz
f_{MAX}	Internal Feedback 1/(t _S + t _{CF})		80		50	MHz
	No Feedback 1/(t _P)		83.3		62.5	MHz
t _{EA}	Input to Output Enable	3	12	3	15	ns
t _{ER}	Input to Output Disable	2	12	2	15	ns
t _{AP}	Input or I/O to Asynchronous Reset of Register	3	13	3	15	ns
t _{SP}	Setup Time, Synchronous Preset	10		10		ns
t _{AW}	Asychronous Reset Width	8		8		ns
t _{AR}	Asychronous Reset Recovery Time	6		6		ns
t _{SPR}	Synchronous Preset to Clock Recovery Time	10		10		ns

Note: 1. See ordering information for valid part numbers.

4.4 Power-down AC Characteristics

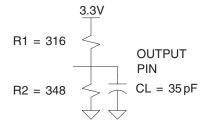
		-	10	-15		
Symbol	Parameter	Min	Max	Min	Max	Units
t _{IVDH}	Valid Input before PD High	10		15		ns
t _{GVDH}	Valid OE before PD High	0		0		ns
t _{CVDH}	Valid Clock before PD High	0		0		ns
t _{DHIX}	Input Don't Care after PD High		10		15	ns
t _{DHGX}	OE Don't Care after PD High		10		15	ns
t _{DHCX}	Clock Don't Care after PD High		10		15	ns
t _{DLIV}	PD Low to Valid Input		10		15	ns
t _{DLGV}	PD Low to Valid $\overline{\text{OE}}$		25		30	ns
t _{DLCV}	PD Low to Valid Clock		25		30	ns
t _{DLOV}	PD Low to Valid Output		30		35	ns

4.5 Input Test Waveforms and Measurement Levels



 $t_{\rm R},\,t_{\rm F}<1.5ns$

4.6 Output Test Loads



Note: Similar competitors devices are specified with slightly different loads. These load differences may affect output signals' delay and slew rate. Atmel devices are tested with sufficient margins to meet compatible device specification conditions.

Table 4-1. Pin Capacitance (f = 1 MHz, T = $25^{\circ}C^{(1)}$)

	Тур	Max	Units	Conditions
C _{IN}	5	8	pF	$V_{IN} = 0V$
C _{OUT}	6	8	pF	$V_{OUT} = 0V$

Note: 1. Typical values for nominal supply voltage. This parameter is only sampled and is not 100% tested.



4.7 Power-up Reset

The registers in the ATF22LV10C are designed to reset during power-up. At a point delayed slightly from V_{CC} crossing V_{RST} , all registers will be reset to the low state. The output state will depend on the polarity of the buffer.

This feature is critical for state machine initialization. However, due to the asynchronous nature of reset and the uncertainty of how V_{CC} actually rises in the system, the following conditions are required:

- 1. The V_{CC} rise must be monotonic and start below 0.7V.
- 2. The clock must remain stable during T_{PR} .
- 3. After T_{PR}, all input and feedback setup times must be met before driving the clock pin high.

4.8 Preload of Register Outputs

The ATF22LV10C registers are provided with circuitry to allow loading of each register with either a high or a low. This feature will simplify testing since any state can be forced into the registers to control test sequencing. A JEDEC file with preload is generated when a source file with vectors is compiled. Once downloaded, the JEDEC file preload sequence will be done automatically by most of the approved programmers after the programming.

5. Electronic Signature Word

There are 64 bits of programmable memory that are always available to the user, even if the device is secured. These bits can be used for user-specific data.

6. Security Fuse Usage

A single fuse is provided to prevent unauthorized copying of the ATF22LV10C fuse patterns. Once programmed, fuse verify and preload are inhibited. However, the 64-bit User Signature remains accessible.

The security fuse should be programmed last, as its effect is immediate.

7. Programming/Erasing

Programming/erasing is performed using standard PLD programmers. See CMOS PLD Programming Hardware & Software Support for information on software/programming.

Table 7-1. Programming/Erasing

Parameter	Description	Тур	Max	Units
T _{PR}	Power-up Reset Time	600	1,000	ns
V _{RST}	Power-up Reset Voltage	2.5	3.0	V

8. Input and I/O Pin-keeper

All ATF22V10C family members have internal input and I/O pin-keeper circuits. Therefore, whenever inputs or I/Os are not being driven externally, they will maintain their last driven state. This ensures that all logic array inputs and device outputs are at known states. These are relatively weak active circuits that can be easily overridden by TTL-compatible drivers (see Input and I/O diagrams on page 8).

12. Ordering Information

12.1 Ordering Information

t _{PD} (ns)	t _S (ns)	t _{co} (ns)	Ordering Code	Package	Operation Range	
			ATF22LV10C-10JC	28J		
10	7.5	7.5	ATF22LV10C-10PC	24P3	Commercial	
10	7.5	7.5	ATF22LV10C-10SC	24S	(0°C to 70°C)	
			ATF22LV10C-10XC	24X		
			ATF22LV10C-10JI	28J		
40	7.5	.5 7.5	ATF22LV10C-10PI	24P3	Industrial	
10	7.5		ATF22LV10C-10SI	24S	(0°C to 85°C)	
			ATF22LV10C-10XI	24X		
				ATF22LV10C-15JC	28J	
	40	12 10	ATF22LV10C-15PC	24P3	Commercial	
	12		ATF22LV10C-15SC	24S	(0°C to 70°C)	
4-			ATF22LV10C-15XC	24X		
15			ATF22LV10C-15JI	28J		
	10	10	ATF22LV10C-15PI	24P3	Industrial	
	12	10	ATF22LV10C-15SI	24S	(-40°C to +85°C)	
			ATF22LV10C-15XI	24X		

12.2 Green Package Options (Pb/Halide-free/RoHS Compliant)

t _{PD} (ns)	t _s (ns)	t _{co} (ns)	Ordering Code	Package	Operation Range
10	7.5	7.5	ATF22LV10C-10JU ATF22LV10C-10PU ATF22LV10C-10SU ATF22LV10C-10XU	28J 24P3 24S 24X	Industrial (0°C to +85°C)

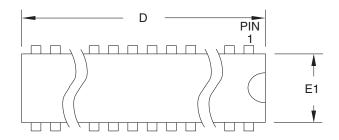
12.3 Using "C" Product for Industrial

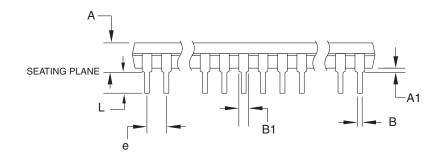
To use commercial product for industrial temperature ranges, simply de-rate I_{CC} by 15% on the "C" device. No speed de-rating is necessary.

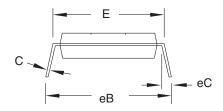
	Package Type						
28J 28-lead, Plastic J-leaded Chip Carrier (PLCC)							
24-lead, 0.300" Wide, Plastic Dual In-line Package (PDIP)							
24S	24-lead, 0.300" Wide, Plastic Gull Wing Small Outline (SOIC)						
24X	24-lead, 4.4 mm Wide, Plastic Thin Shrink Small Outline (TSSOP)						



13.2 24P3 - PDIP







Notes:

- 1. This package conforms to JEDEC reference MS-001, Variation AF.
- Dimensions D and E1 do not include mold Flash or Protrusion. Mold Flash or Protrusion shall not exceed 0.25 mm (0.010").

COMMON DIMENSIONS

(Unit of Measure = mm)

SYMBOL	DL MIN NOM		MAX	NOTE
А	_	-	5.334	
A1	0.381		_	
D	31.623	_	32.131	Note 2
Е	7.620	-	8.255	
E1	6.096	_	7.112	Note 2
В	0.356	_	0.559	
B1	1.270	_	1.651	
L	2.921		3.810	
С	0.203	_	0.356	
eB	eB –		10.922	
eC	0.000	_	1.524	
е				



TITLE

24P3, 24-lead (0.300"/7.62 mm Wide) Plastic Dual Inline Package (PDIP)

DRAWING NO.

24P3

